

HSI-CHIN ELECTRONICS CO., LTD. Report No. : CE/2005/86895

4F, NO. 194, SEC. 3, TA TUNG RD., HSI CHIH CITY, TAIPEI Date : 2005/09/06

HSIEN, TAIWAN R. O. C. Page : 1 of 6

The following merchandise was (were) submitted and identified by the client as:

Type of Product : PLASTIC PARTS: USB SERIES (GP)

Buyer/Order No : SONY

Sample Received : 2005/08/30

Testing Date : 2005/08/30 TO 2005/09/06

Test Result : - Please see the next page -

Daniel Yeh, M.R. Operation Man Signed for and on behalf of SGS TAIWAN LTD.



HSI-CHIN ELECTRONICS CO., LTD. Report No. : CE/2005/86895

4F, NO. 194, SEC. 3, TA TUNG RD., HSI CHIH CITY, TAIPEI Date : 2005/09/06

HSIEN, TAIWAN R. O. C. Page : 2 of 6

Test Result

PART NAME NO.1 : BLACK PLASTIC (PLEASE REFER TO THE PHOTO ATTACHED)

Test Item (s):	Unit	Madh a d	MDL	Result
		Method		No.1
Monobromobiphenyl	%		0.0005	N.D.
Dibromobiphenyl	%	1	0.0005	N.D.
Tribromobiphenyl	%	7	0.0005	N.D.
Tetrabromobiphenyl	%	With reference to USEPA3540C or USEPA3550C. Analysis was performed by HPLC/DAD, LC/MS or GC/MS. (prohibited by 2002/95/EC (RoHS), 83/264/EEC, and 76/769/EEC)	0.0005	N.D.
Pentabromobiphenyl	%		0.0005	N.D.
Hexabromobiphenyl	%		0.0005	N.D.
Heptabromobiphenyl	%		0.0005	N.D.
Octabromobiphenyl	%		0.0005	N.D.
Nonabromobiphenyl	%		0.0005	N.D.
Decabromobiphenyl	%		0.0005	N.D.
Total PBBs	%		-	N.D.
(Polybrominated				
biphenyls)/Sum of above				
Monobromobiphenyl ether	%	With reference to USEPA3540C or USEPA3550C. Analysis was performed by HPLC/DAD, LC/MS or GC/MS. (prohibited by 2002/95/EC (RoHS), 83/264/EEC, and 76/769/EEC)	0.0005	N.D.
Dibromobiphenyl ether	%		0.0005	N.D.
Tribromobiphenyl ether	%		0.0005	N.D.
Tetrabromobiphenyl ether	%		0.0005	N.D.
Pentabromobiphenyl ether	%		0.0005	N.D.
Hexabromobiphenyl ether	%		0.0005	N.D.
Heptabromobiphenyl ether	%		0.0005	N.D.
Octabromobiphenyl ether	%		0.0005	N.D.
Nonabromobiphenyl ether	%		0.0005	N.D.
Decabromobiphenyl ether	%		0.0005	N.D.
Total PBBEs	%		-	N.D.
(PBDEs)(Polybrominated biphenyl ethers)/Sum of above				



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4F, NO. 194, SEC. 3, TA TUNG RD., HSI CHIH CITY, TAIPEI Date : 2005/09/06

HSIEN, TAIWAN R. O. C. Page : 3 of 6

Test Item (s):	TT 34	Method	MDL	Result
	Unit			No.1
Chromium VI (Cr+6)	ppm	UV-VIS after reference to US EPA 3060A.	2	N.D.
Cadmium (Cd)	ppm	ICP-AES after reference to EN 1122, method B:2001 or other acid digestion.	2	N.D.
Mercury (Hg)	ppm	ICP-AES after reference to US EPA 3052 or other acid digestion.	2	N.D.
Lead (Pb)	ppm	ICP-AES after reference to US EPA 3050B or other acid digestion.	2	11.1

NOTE: (1) N.D. = Not detected (<MDL)

- (2) ppm = mg/kg
- (3) MDL = Method Detection Limit
- (4) " " = No Regulation



HSI-CHIN ELECTRONICS CO., LTD. Report No. : CE/2005/86895

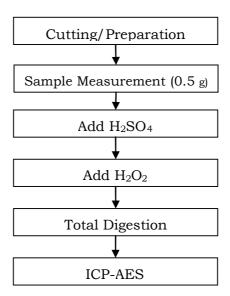
4F, NO. 194, SEC. 3, TA TUNG RD., HSI CHIH CITY, TAIPEI Date : 2005/09/06

HSIEN, TAIWAN R. O. C. Page : 4 of 6

Per requirements of SONY QAR-05-002:

- 1) These samples were dissolved totally by pre-conditioning method according to below flow chart.
- 2) Name of the person who made measurement: Anren Lee
- 3) Name of the person in charge of measurement: Daniel Yeh

Flow Chart of Digestion for Plastic - EN1122 for Cd (without residue)





Report No. : CE/2005/86895 HSI-CHIN ELECTRONICS CO., LTD.

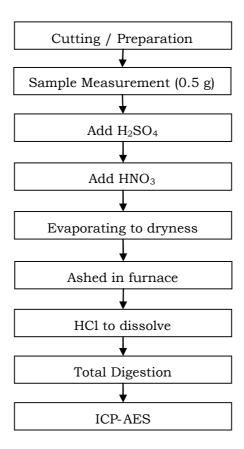
4F, NO. 194, SEC. 3, TA TUNG RD., HSI CHIH CITY, TAIPEI Date : 2005/09/06

HSIEN, TAIWAN R. O. C. Page : 5 of 6

Per requirements of SONY QAR-05-002:

- 1) These samples were dissolved totally by pre-conditioning method according to below flow chart.
- 2) Name of the person who made measurement: Anren Lee
- 3) Name of the person in charge of measurement: Daniel Yeh

Flow Chart of Digestion for Plastic -Wet Decomposition for Pb (without residue)



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4F, NO. 194, SEC. 3, TA TUNG RD., HSI CHIH CITY, TAIPEI Date : 2005/09/06

HSIEN, TAIWAN R. O. C. Page: 6 of 6

